FORM PTO 1449 (modified)

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary)

Submitted to the PTO: November 30, 2007

ATTY DOCKET NO. 03500.017774	application no. 10/535,452
APPLICANTS MIKI OGAWA, ET AL.	

GROUP

1765

FILING DATE May 19, 2005

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*EXAMINER	DOCUMENT	.				FILING DATE
INITIAL	NUMBER	DATE	NAME	CLASS	SUBCLASS	IF APPROPRIATE
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Sheet<u>2</u> of <u>2</u>

Abstract

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